

## 2D triangular Mott Hubbard insulator state of Sn/Si(111) and Sn/Ge(111) surfaces

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### Content

### Summary

**Primary author(s) :** E. TOSATTI (SISSA & ICTP, Trieste, Italy)

**Presenter(s) :** E. TOSATTI (SISSA & ICTP, Trieste, Italy)

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